



60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
60V	7.3mΩ @ V _{GS} = 10V	95A
607	15mΩ @ V _{GS} = 4.5V	67A

Features and Benefits

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Rds(ON)—Minimizes Power Losses
- Low Q_q—Minimizes Switching Losses
- < 1.1mm Package Profile—Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

Description and Applications

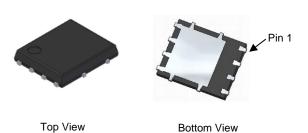
This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

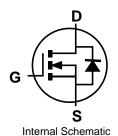
- Power-management functions
- DC-DC converters
- Backlighting

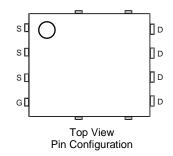
Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- · Weight: 0.097 grams (Approximate)









Ordering Information (Note 4)

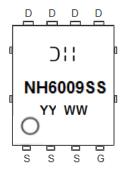
Orderable Part Number	Paskage	Packing		
Orderable Part Number	Package	Qty.	Carrier	
DMNH6009SPS-13	PowerDI5060-8	2500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



Dill = Manufacturer's Marking
NH6009SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 24 = 2024)
WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V_{DSS}	60	V
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Note 5) V _{GS} = 10V	T _C = +25°C T _C = +100°C	l _D	95 67	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)	I _{DM}	380	Α	
Maximum Continuous Body Diode Forward Current (Note 5)	Is	95	Α	
Pulsed Source Current (380µs Pulse, Duty Cycle = 1%)	Isм	380	Α	
Avalanche Current, L = 0.1mH (Note 6)	las	56	Α	
Avalanche Energy, L = 0.1mH (Note 6)	Eas	226	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 7)		P _D	1.6	W	
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	RθJA	95	°C/W	
Total Power Dissipation (Note 8)	PD	3.3	W		
Thermal Resistance, Junction to Ambient (Note 8) Steady State		Reja	46	°C/W	
Thermal Resistance, Junction to Case (Note 5)		R ₀ JC	1.5	1 0/00	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C	

Notes:

- 5. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 6. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.
- 7. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.
- 8. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	V _G S = 0V, I _D = 1mA	
Zero Gate Voltage Drain Current, T _J = +25°C	IDSS	_	_	1	μΑ	V _{DS} = 48V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)	ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	Vgs(TH)	1	2	3	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	4.6	7.3	mΩ	$V_{GS} = 10V, I_D = 50A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	7.1	15	mΩ	$V_{GS} = 4.5V, I_D = 25A$	
Diode Forward Voltage	VsD	_	0.7	1.2	V	V _G S = 0V, I _S = 1.7A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	-	1882	_	pF		
Output Capacitance	Coss		374	_	pF	V _{DS} = 30V, V _{GS} = 0V f = 1MHz	
Reverse Transfer Capacitance	Crss		111	_	pF		
Gate Resistance	Rg		2.1	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg		18.5	_	nC		
Total Gate Charge (VGS = 10V)	Qg		37.3	_	nC	V _{DS} = 30V, I _D = 25A	
Gate-Source Charge	Qgs		5.0	_	nC		
Gate-Drain Charge	Q_{gd}		11.2	_	nC		
Turn-On Delay Time	tD(ON)		5.7	_	ns		
Turn-On Rise Time	t _R		7.5	_	ns	$V_{GS} = 10V, V_{DS} = 30V$ $R_g = 3\Omega, I_D = 25A$	
Turn-Off Delay Time	tD(OFF)		16.9	_	ns		
Turn-Off Fall Time	t _F	_	6.3	_	ns		
Body Diode Reverse-Recovery Time	t _{RR}		32	_	ns	I _F = 25A, di/dt = 100A/μs	
Body Diode Reverse-Recovery Charge	Qrr	_	30	_	nC		

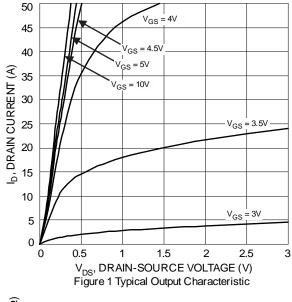
Notes:

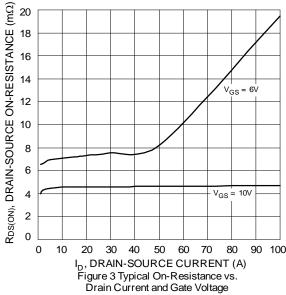
^{9.} Short duration pulse test used to minimize self-heating effect.

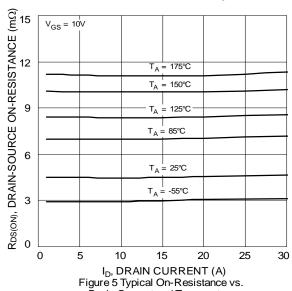
^{10.} Guaranteed by design. Not subject to product testing.



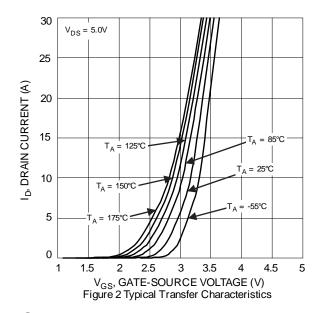


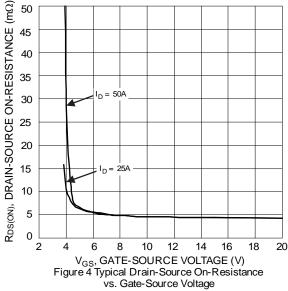


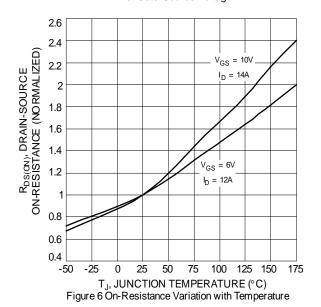




Drain Current and Temperature

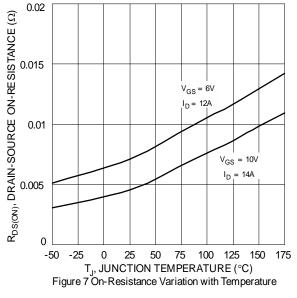


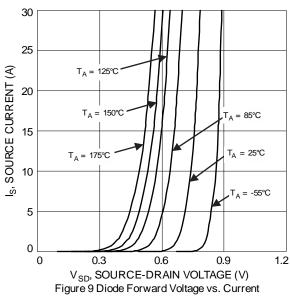


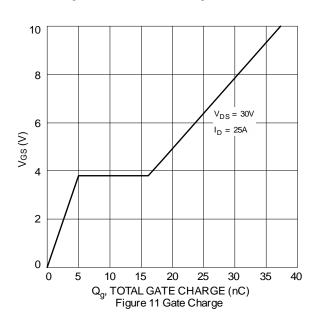












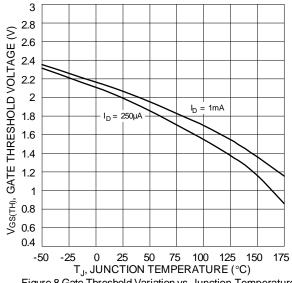
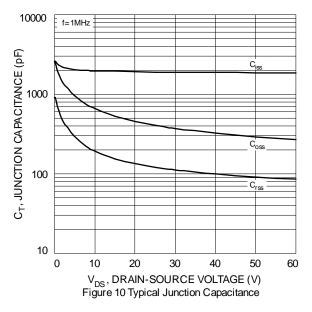
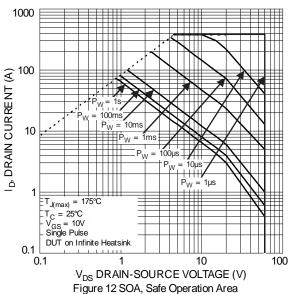
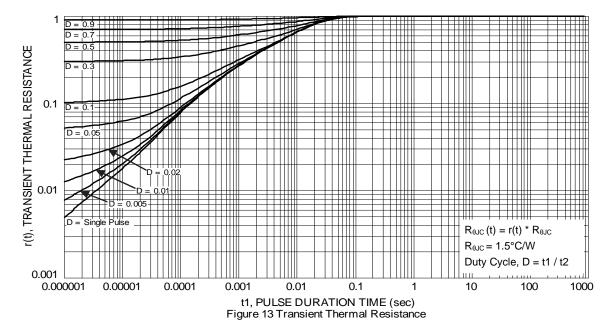


Figure 8 Gate Threshold Variation vs. Junction Temperature







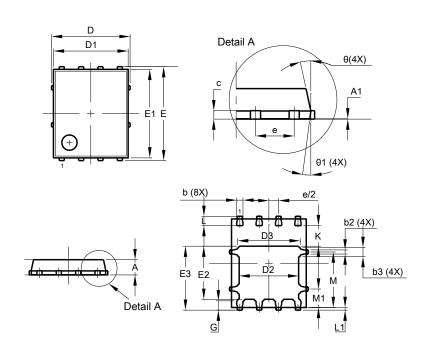




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

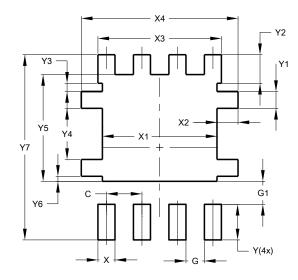


	PowerDI5060-8				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	,	5.15 BSC	,		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	3.90 4.30 4.1			
Е	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е		1.27 BSC			
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
M	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7 6.610				



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